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1c685 U.S. PTO

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UTILITY PATENT APPLICATION  
UNDER 37 CFR 1.53(b)

Box PATENT APPLICATION  
Assistant Commissioner for Patents  
Washington, DC 20231

Case Docket No. 43890-449

Sir:

Transmitted herewith for filing is the patent application of:

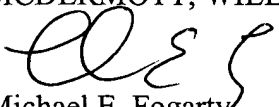
INVENTOR: Hidenori KAMEI, Shuichi SHINAGAWA, Hidemi TAKEISHI  
FOR: P-TYPE NITRIDE SEMICONDUCTOR AND METHOD OF  
MANUFACTURING THE SAME

Enclosed are:

- ☒ 39 pages of specification, claims, abstract.
- ☐ Declaration and Power of Attorney.
- ☒ Priority Claimed.
- ☒ Certified copy of Japanese Patent Application No. 11-293319 and Japanese Patent Application No. 2000-212356
- ☒ 6 sheets of formal drawing.
- ☐ An assignment of the invention to \_\_\_\_\_  
and the assignment recordation fee.
- ☐ An associate power of attorney.
- ☒ Information Disclosure Statement, Form PTO-1449 and reference.
- ☒ Return Receipt Postcard
- ☐

Respectfully submitted,

MCDERMOTT, WILL & EMERY

  
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